Preferred Device

Silicon Controlled Rectifiers

Reverse Blocking Thyristors

Designed for high volume, low cost, industrial and consumer applications such as motor control; process control; temperature, light and speed control.

- Small Size
- Passivated Die for Reliability and Uniformity
- Low Level Triggering and Holding Characteristics
- Device Marking: Device Type, e.g., for MCR12DCM: R12DCM, Date Code

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage ⁽¹⁾ (T _J = -40 to 125°C, Sine Wave, 50 to 60 Hz, Gate Open)	VDRM, VRRM		Volts
MCR12DCM MCR12DCN		600 800	
On–State RMS Current (180° Conduction Angles; T _C = 90°C)	IT(RMS)	12	Amps
Average On–State Current (180° Conduction Angles; T _C = 90°C)	l _{T(AV)}	7.6	Amps
Peak Non-Repetitive Surge Current (1/2 Cycle, Sine Wave 60 Hz, T _J = 125°C)	ITSM	100	Amps
Circuit Fusing Consideration (t = 8.3 msec)	I ² t	41	A ² sec
Forward Peak Gate Power (Pulse Width ≤ 1.0 µsec, T _C = 90°C)	PGM	5.0	Watts
Forward Average Gate Power (t = 8.3 msec, T _C = 90°C)	PG(AV)	0.5	Watts
Forward Peak Gate Current (Pulse Width ≤ 1.0 μsec, T _C = 90°C)	I _{GM}	2.0	Amps
Operating Junction Temperature Range	TJ	-40 to 125	°C
Storage Temperature Range	T _{stg}	-40 to 150	°C

(1) V_{DRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the device are exceeded.



ON Semiconductor

http://onsemi.com

SCRs 12 AMPERES RMS 600 thru 800 VOLTS





D-PAK CASE 369A STYLE 4

PIN ASSIGNMENT				
1 Cathode				
2	Anode			
3	Gate			
4	Anode			

ORDERING INFORMATION

Device	Package	Shipping
MCR12DCMT4	DPAK 369A	16mm Tape and Reel (2.5K/Reel)
MCR12DCNT4	DPAK 369A	16mm Tape and Reel (2.5K/Reel)

Preferred devices are recommended choices for future use and best overall value.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance — Junction to Case — Junction to Ambient — Junction to Ambient ⁽¹⁾	R _Ð JC R _Ð JA R _Ð JA	2.2 88 80	°C/W
Maximum Lead Temperature for Soldering Purposes(2)	TL	260	°C

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit		
OFF CHARACTERISTICS							
Peak Repetitive Forward or Reverse Blocking Current (VAK = Rated VDRM or VRRM, Gate Open)	T _J = 25°C T _J = 125°C	I _{DRM,} I _{RRM}	=	_	0.01 5.0	mA	
ON CHARACTERISTICS							
Peak Forward On–State Voltage ⁽³⁾ (I _{TM} = 20 A)		Vтм	_	1.3	1.9	Volts	
Gate Trigger Current (Continuous dc) $(V_D = 12 \text{ V}, R_L = 100 \Omega)$	$T_{J} = 25^{\circ}C$ $T_{J} = -40^{\circ}C$	l _{GT}	2.0	7.0 —	20 40	mA	
Gate Trigger Voltage (Continuous dc) $(V_D = 12 \text{ V}, R_L = 100 \Omega)$	$T_{J} = 25^{\circ}C$ $T_{J} = -40^{\circ}C$	V _G T	0.5 —	0.65 —	1.0 2.0	Volts	
Gate Non–Trigger Voltage $(V_D = 12 \text{ V, R}_L = 100 \Omega)$	T _J = 125°C	V _{GD}	0.2	_	_	Volts	
Holding Current (V _D = 12 V, Initiating Current = 200 mA, Gate Open)	T _J = 25°C T _J = -40°C	Ιн	4.0 —	22 —	40 80	mA	
Latching Current $(V_D = 12 \text{ V}, I_G = 20 \text{ mA}, T_J = 25^{\circ}\text{C})$ $(V_D = 12 \text{ V}, I_G = 40 \text{ mA}, T_J = -40^{\circ}\text{C})$		ΙL	4.0 —	22 —	40 80	mA	

DYNAMIC CHARACTERISTICS

Characteristic	Symbol	Min	Тур	Max	Unit
Critical Rate of Rise of Off–State Voltage (V _D = Rated V _{DRM} , Exponential Waveform, Gate Open, T _J = 125°C)	dv/dt	50	200		V/μs

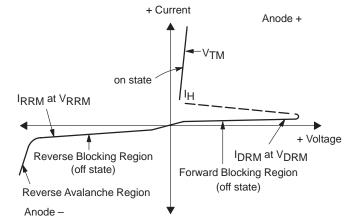
⁽¹⁾ Surface mounted on minimum recommended pad size.

^{(2) 1/8&}quot; from case for 10 seconds.

⁽³⁾ Pulse Test: Pulse Width \leq 2.0 msec, Duty Cycle \leq 2%.

Voltage Current Characteristic of SCR

Symbol	Parameter
VDRM	Peak Repetitive Off State Forward Voltage
IDRM	Peak Forward Blocking Current
VRRM	Peak Repetitive Off State Reverse Voltage
I _{RRM}	Peak Reverse Blocking Current
V _{TM}	Peak On State Voltage
lΗ	Holding Current



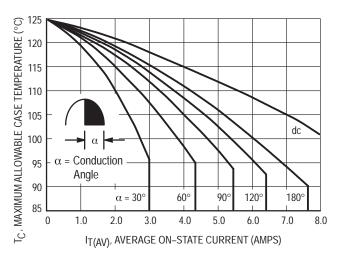


Figure 1. Average Current Derating

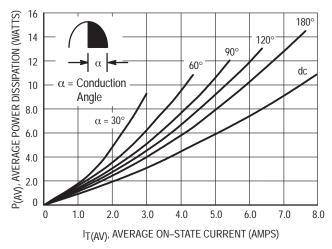
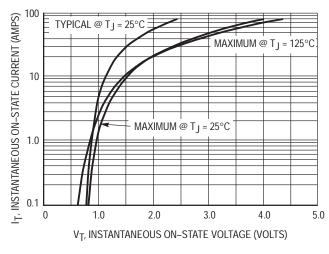


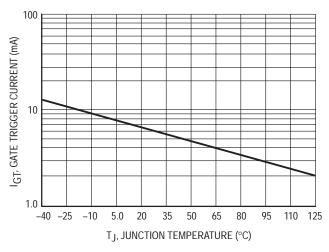
Figure 2. On-State Power Dissipation



1.0 (NORWALIZED) 0.01 (1.0 10 100 1000 10 K t, TIME (ms)

Figure 3. On-State Characteristics

Figure 4. Transient Thermal Response





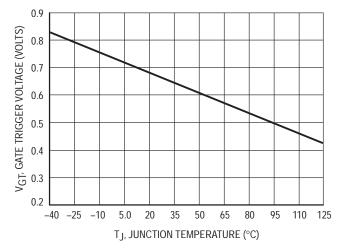
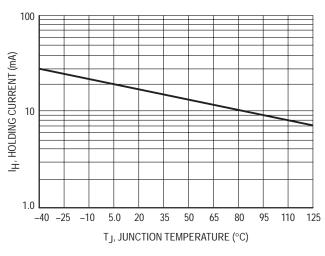


Figure 6. Typical Gate Trigger Voltage versus Junction Temperature



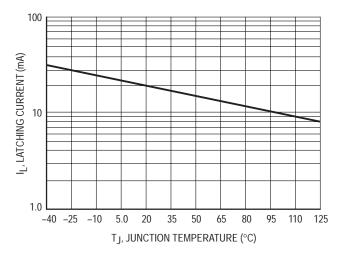


Figure 7. Typical Holding Current versus Junction Temperature

Figure 8. Typical Latching Current versus Junction Temperature

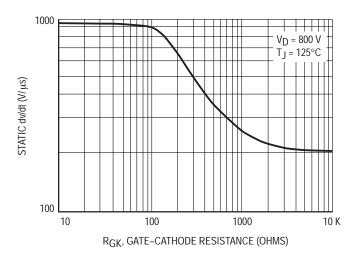
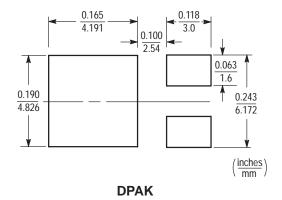


Figure 9. Exponential Static dv/dt versus Gate–Cathode Resistance

MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

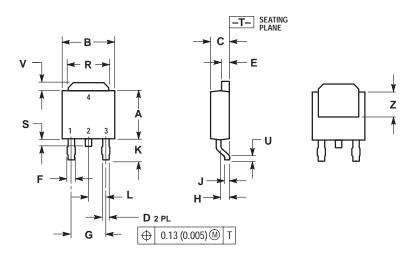
Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to insure proper solder connection

interface between the board and the package. With the correct pad geometry, the packages will self align when subjected to a solder reflow process.



PACKAGE DIMENSIONS

D-PAK CASE 369A-13 ISSUE Z



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

	INC	HES	MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.235	0.250	5.97	6.35
В	0.250	0.265	6.35	6.73
С	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
Е	0.033	0.040	0.84	1.01
F	0.037	0.047	0.94	1.19
G	0.180 BSC		4.58	BSC
Н	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.102	0.114	2.60	2.89
L	0.090	0.090 BSC		BSC
R	0.175	0.215	4.45	5.46
S	0.020	0.050	0.51	1.27
U	0.020		0.51	
V	0.030	0.050	0.77	1.27
Z	0.138		3.51	

STYLE 4: PIN 1. CATHODE 2. ANODE 3. GATE 4. ANODE

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JAPAN: ON Semiconductor, Japan Customer Focus Center 4–32–1 Nishi–Gotanda, Shinagawa–ku, Tokyo, Japan 141–0031

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